NJD35N04G, NJVNJD35N04G, NJVNJD35N04T4G

NPN Darlington Power Transistor

This high voltage power Darlington has been specifically designed for inductive applications such as Electronic Ignition, Switching Regulators and Motor Control.

Features

- Exceptional Safe Operating Area
- High V_{CE}; High Current Gain
- NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These are Pb-Free Devices*

Benefits

- Reliable Performance at Higher Powers
- Designed for Inductive Loads
- Very Low Current Requirements

Applications

- Internal Combustion Engine Ignition Control
- Switching Regulators
- Motor Controls
- Light Ballast
- Photo Flash

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Sustaining Voltage	V _{CEO}	350	Vdc
Collector-Base Breakdown Voltage	V _{CBO}	700	Vdc
Collector-Emitter Breakdown Voltage	V _{CES}	700	Vdc
Emitter-Base Voltage	V _{EBO}	5.0	Vdc
Collector Current Continuous Peak	I _C	4.0 8.0	Adc
Base Current	I _B	0.5	Adc
Total Power Dissipation @ T _C = 25°C Derate above 25°C	P _D	45 0.36	W W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



ON Semiconductor®

http://onsemi.com

DARLINGTON
POWER TRANSISTORS
4 AMPERES
350 VOLTS
45 WATTS



DPAK CASE 369C STYLE 1

MARKING DIAGRAM



Y = Year WW = Work Week NJD35N04 = Device Code G = Pb-Free Device

ORDERING INFORMATION

Device	Package	Shipping [†]
NJD35N04G	DPAK (Pb-Free)	75 Units / Rail
NJVNJD35N04G	DPAK (Pb-Free)	75 Units / Rail
NJD35N04T4G	DPAK (Pb-Free)	2,500 / Tape & Reel
NJVNJD35N04T4G	DPAK (Pb-Free)	2,500 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance Junction-to-Case Junction-to-Ambient	$egin{array}{c} {\sf R}_{ heta {\sf JC}} \ {\sf R}_{ heta {\sf JA}} \end{array}$	2.78 71.4	°C/W

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					L
Collector-Emitter Sustaining Voltage (I _C = 10 mA, L = 10 mH)	V _{CEO(sus)}	350	-	-	V
Collector Cutoff Current ($V_{CE} = 500 \text{ V}$) ($I_B = 0$) ($V_{CE} = 500 \text{ V}$, $T_C = 125^{\circ}\text{C}$)	I _{CES}	- -		50 250	μΑ
Collector Cutoff Current ($V_{CE} = 250 \text{ V}$) ($I_B = 0$) ($V_{CE} = 200 \text{ V}$, $T_C = 125^{\circ}\text{C}$)	I _{CEO}	- -	<u>-</u> -	50 250	μΑ
Emitter Cutoff Current (V _{BE} = 5.0 Vdc)	I _{EBO}	-	-	5.0	μΑ
ON CHARACTERISTICS	'			1	
Collector–Emitter Saturation Voltage (I_C = 2.0 A, I_B = 20 mA) (I_C = 2.0 A, I_B = 20 mA 125°C)	V _{CE(sat)}	- -	- -	1.5 1.5	V
Base–Emitter Saturation Voltage (I_C = 2.0 A, I_B = 20 mA) (I_C = 2.0 A, I_B = 20 mA 125°C)	V _{BE(sat)}	- -	- -	2.0 2.0	V
Base–Emitter On Voltage (I _C = 2.0 A, V _{CE} = 2.0 V) (I _C = 2.0 A, V _{CE} = 2.0 V∏ 25°C)	V _{BE(on)}	- -	- -	2.0 2.0	V
DC Current Gain (I _C = 2.0 A, V _{CE} = 2.0 V) (I _C = 4.0 A, V _{CE} = 2.0 Vdc)	h _{FE}	2000 300	_ _	_ _ _	-
DYNAMIC CHARACTERISTICS			!	!	!
Current–Gain – Bandwidth Product (I _C = 2.0 A, V _{CE} = 10 V, f = 1.0 MHz)	f _T	90	_	_	MHz
Output Capacitance (V _{CB} = 10 V, I _E = 0, f = 0.1 MHz)	C _{ob}	-	60	-	pF
SWITCHING CHARACTERISTICS	•		•	•	•
V _{CC} = 12 V, V _{clamp} = 250 V, L = 4 mH I _C = 2 A, I _{B1} = 20 mA, I _{B2} = -20 mA	t _s	- -	18 0.8	- -	μSec

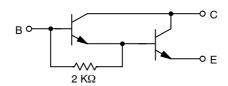


Figure 1. Darlington Circuit Schematic

NJD35N04G, NJVNJD35N04G, NJVNJD35N04T4G

TYPICAL CHARACTERISTICS

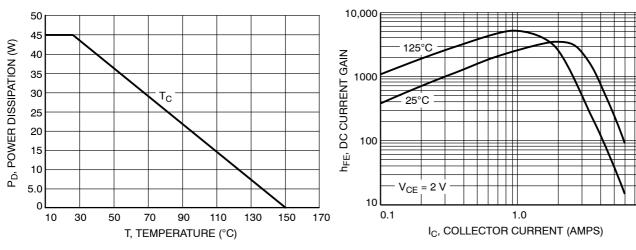


Figure 2. Power Derating

Figure 3. DC Current Gain

10

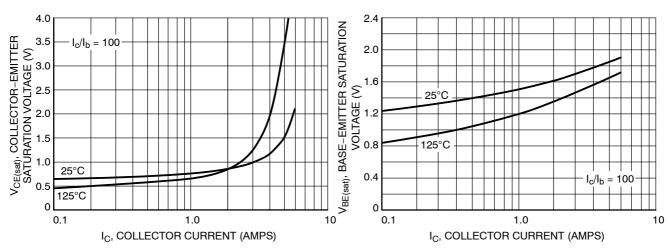


Figure 4. Collector-Emitter Saturation Voltage

Figure 5. Base-Emitter Saturation Voltage

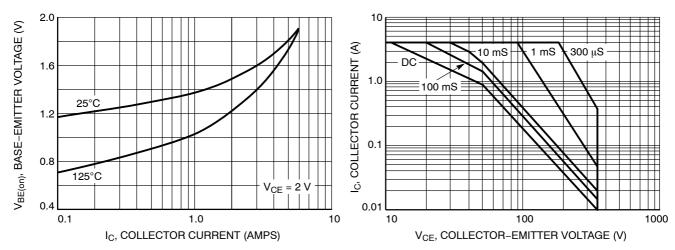
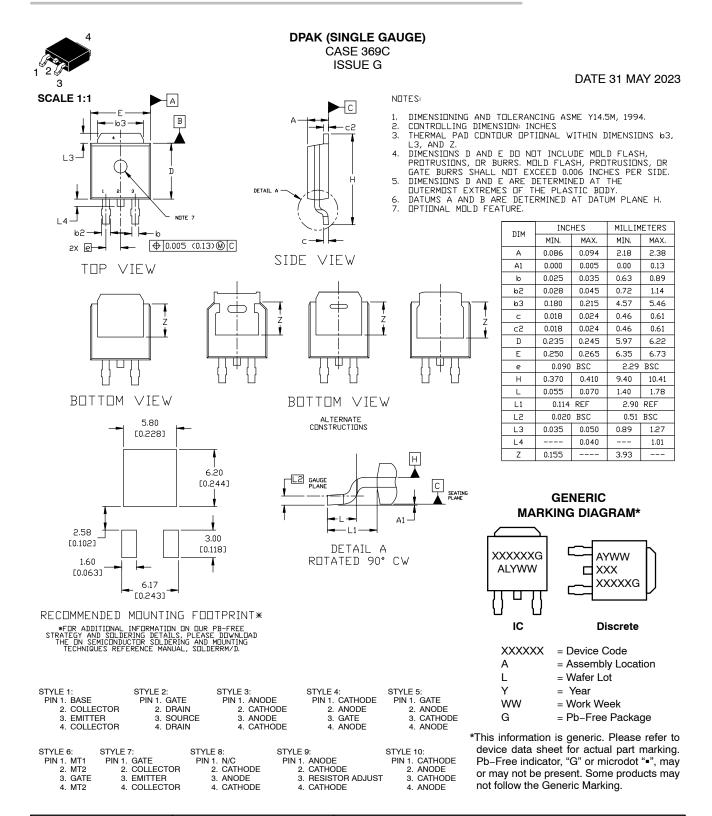


Figure 6. Base-Emitter Voltage

Figure 7. Forward Bias Safe Operating Area (FBSOA)





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